## MOTOROLA SEMICONDUCTOR TECHNICAL DATA

#### MC68HC05P4

# Addendum to MC68HC05P4 HCMOS Microcontroller Unit Technical Data

This addendum supplements *MC68HC05P4 Technical Data* (Motorola document number MC68HC05P4/D) with the following additional information:

- DC Electrical Characteristics
- MC68HCL05P4 data APPENDIX A contains data for the MC68HCL05P4, a low-power version of the MC68HC05P4
- MC68HSC05P4 data APPENDIX B contains data for the MC68HSC05P4, a high-speed version
  of the MC68HC05P4

Specifications and information herein are subject to change without notice.



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#### 9.4 DC ELECTRICAL CHARACTERISTICS

The following table replaces Table 9-3 in MC68HC05P4 Technical Data.

Table 9-3. DC Electrical Characteristics ( $V_{DD} = 5.0 \text{ Vdc} \pm 10\%$ )

Characteristic	Symbol	Min	Typ <sup>(1)</sup>	Max	Unit
Output Voltage $I_{LOAD} = 10.0 \mu A$ $I_{LOAD} = -10.0 \mu A$	V <sub>OL</sub> V <sub>OH</sub>	 V <sub>DD</sub> - 0.1		0.1 —	V V
Output High Voltage (I <sub>LOAD</sub> = -0.8 mA) PA7-PA0, PB7-PB5, PC7-PC0, PD5, TCMP	V <sub>OH</sub>	V <sub>DD</sub> - 0.8	_	_	٧
Output Low Voltage (I <sub>LOAD</sub> = 1.6 mA) PA7-PA0, PB7-PB5, PC7-PC0, PD5, TCMP	V <sub>OL</sub>	_	_	0.4	v
Input High Voltage PA7-PA0, PB7-PB5, PC7-PC0, PD5, PD7/TCAP, IRQ, RESET, OSC1	V <sub>IH</sub>	0.7 × V <sub>DD</sub>	_	V <sub>DD</sub>	v
Input Low Voltage PA7-PA0, PB7-PB5, PC7-PC0, PD5, PD7/TCAP, IRQ, RESET, OSC1	V <sub>IL</sub>	V <sub>ss</sub>	_	0.2 × V <sub>DD</sub>	v
Data-Retention Mode Supply Voltage	V <sub>RM</sub>	2	_		V
Supply Current Run <sup>(2)</sup> WAIT <sup>(3)</sup> STOP <sup>(4)</sup> 25 °C 0 to 70 °C (Standard)	I <sub>DD</sub>	_ _ _	3.1 1.1 2.25	7.0 4.0 50 140	mA mA μA μA
I/O Ports High-Z Leakage Current PA7-PA0, PB7-PB5, PC7-PC0, PD5	I <sub>IL</sub>			±10	μА
Input Current RESET, IRQ, OSC1, PD7/TCAP	I <sub>IN</sub>			±1	μА
Capacitance Ports (Input or Output) RESET, IRQ, PD5, PD7/TCAP	C <sub>OUT</sub>			12 8	pF pF

<sup>1.</sup> Typical values at midpoint of voltage range, 25 °C only.

<sup>2.</sup> Run (operating)  $I_{DD}$  measured using external square wave clock source ( $f_{OSC}$  = 4.2 MHz). All inputs 0.2 V from rail. No dc loads. Less than 50 pF on all outputs.  $C_L = 20$  pF on OSC2.

<sup>3.</sup> WAIT  $I_{DD}$  measured using external square wave clock source ( $f_{OSC}$  = 4.2 MHz). All inputs 0.2 V from rail. No dc loads. Less than 50 pF on all outputs. CL = 20 pF on OSC2. All ports configured as inputs.  $V_{IL}$  = 0.2 V.  $V_{IH} = V_{DD}$  - 0.2 V. OSC2 capacitance linearly affects WAIT  $I_{DD}$ . 4. STOP  $I_{DD}$  measured with OSC1 =  $V_{SS}$ . All ports configured as inputs.  $V_{IL} = 0.2$  V.  $V_{IH} = V_{DD}$  - 0.2 V.

The following table replaces Table 9-4 in MC68HC05P4 Technical Data.

Table 9-4. DC Electrical Characteristics ( $V_{DD} = 3.3 \text{ Vdc} \pm 10\%$ )

Characteristic	Symbol	Min	Typ <sup>(1)</sup>	Max	Unit
Output Voltage I <sub>LOAD</sub> = 10.0 μA I <sub>LOAD</sub> = -10.0 μA	V <sub>OL</sub>	 V <sub>DD</sub> - 0.1	<u>-</u>	0.1 —	V V
Output High Voltage (I <sub>LOAD</sub> = -0.2 mA) PA7-PA0, PB7-PB5, PC7-PC0, PD5, TCMP	V <sub>OH</sub>	V <sub>DD</sub> - 0.3	_	_	V
Output Low Voltage (I <sub>LOAD</sub> = 0.4 mA) PA7-PA0, PB7-PB5, PC7-PC0, PD5, TCMP	V <sub>OL</sub>	_	_	0.3	V
Input High Voltage PA7-PA0, PB7-PB5, PC7-PC0, PD5, PD7/TCAP, IRQ, RESET, OSC1	V <sub>IH</sub>	0.7 × V <sub>DD</sub>	_	V <sub>DD</sub>	V
Input Low Voltage PA7-PA0, PB7-PB5, PC7-PC0, PD5, PD7/TCAP, IRQ, RESET, OSC1	V <sub>IL</sub>	V <sub>ss</sub>	_	0.2 × V <sub>DD</sub>	V
Supply Current Run <sup>(2)</sup> WAIT <sup>(3)</sup> STOP <sup>(4)</sup>	I <sub>DD</sub>	=	0.8 0.35	2.5 1.4 30	mA mA
25 °C 0 to 70 °C (Standard)		_	0.6 —	80	μ <b>Α</b> μ <b>Α</b>
I/O Ports High-Z Leakage Current PA7-PA0, PB7-PB5, PC7-PC0, PD5	I <sub>IL</sub>		_	±10	μА
Input Current RESET, IRQ, OSC1, PD7/TCAP	I <sub>IN</sub>		_	±1	μА
Capacitance Ports (Input or Output) RESET, IRQ, PD5, PD7/TCAP	C <sub>OUT</sub> C <sub>IN</sub>		_	12 8	pF pF

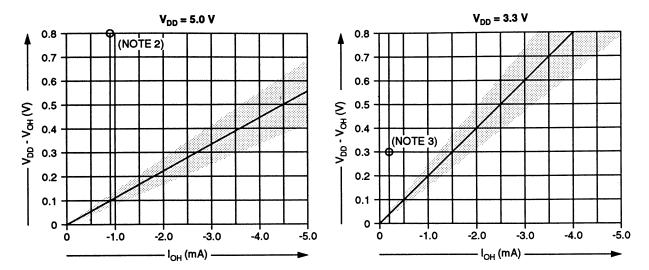
<sup>1.</sup> Typical values at midpoint of voltage range, 25 °C only.

4. STOP  $I_{DD}$  measured with OSC1 =  $V_{SS}$ . All ports configured as inputs.  $V_{IL}$  = 0.2 V.  $V_{IH}$  =  $V_{DD}$  - 0.2 V.

<sup>2.</sup> Run (operating)  $I_{DD}$  measured using external square wave clock source ( $f_{OSC}$  = 2.1 MHz). All inputs 0.2 V from rail. No dc loads. Less than 50 pF on all outputs.  $C_L$  = 20 pF on OSC2.

<sup>3.</sup> WAIT  $I_{DD}$  measured using external square wave clock source ( $f_{OSC} = 2.1$  MHz). All inputs 0.2 V from rail. No dc loads. Less than 50 pF on all outputs.  $C_L = 20$  pF on OSC2. All ports configured as inputs.  $V_{IL} = 0.2$  V.  $V_{IH} = V_{DD}$  - 0.2 V. OSC2 capacitance linearly affects WAIT  $I_{DD}$ .

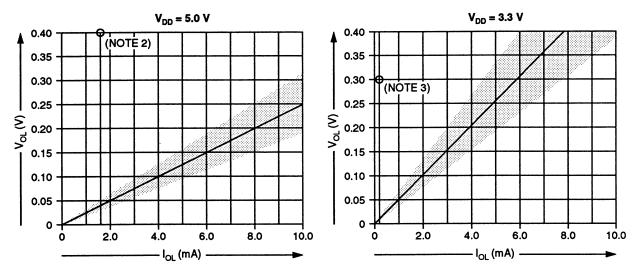
The following figures replace Figure 9-2 and Figure 9-3 of MC68HC05P4 Technical Data.



#### NOTES:

- 1. Shaded area indicates variation in driver characteristics due to changes in temperature and for normal processing tolerances. Within the limited range of values shown, V vs I curves are approximately straight lines.
- 2. At  $V_{DD}$  = 5.0 V, devices are specified and tested for  $V_{OH} \ge V_{DD}$  800 mV @  $I_{OH}$  = -0.8 mA.
- 3. At V<sub>DD</sub> = 3.3 V, devices are specified and tested for V<sub>OH</sub>  $\geq$  V<sub>DD</sub> 300 mV @ I<sub>OH</sub> = -0.2 mA.

Figure 9-2. Typical High-Side Driver Characteristics



#### NOTES:

- 1. Shaded area indicates variation in driver characteristics due to changes in temperature and for normal processing tolerances. Within the limited range of values shown, V vs I curves are approximately straight lines.
- 2. At  $V_{DD}$  = 5.0 V, devices are specified and tested for  $V_{OL} \le$  400 mV @  $I_{OL}$  = 1.6 mA.
- 3. At  $V_{DD}$  = 3.3 V, devices are specified and tested for  $V_{OL} \le$  300 mV @  $I_{OL}$  = 0.4 mA.

Figure 9-3. Typical Low-Side Driver Characteristics

The following figures replace Figure 9-4 and Figure 9-5 in MC68HC04P4 Technical Data.

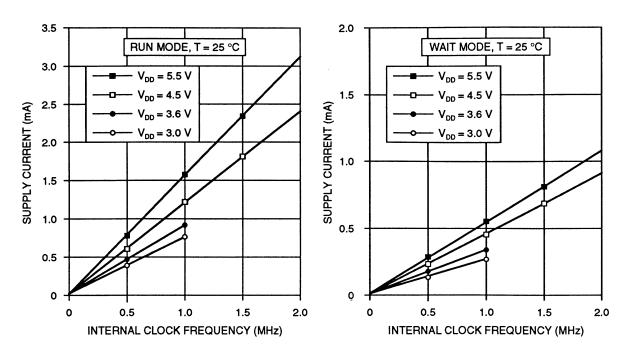


Figure 9-4. Typical Supply Current vs Internal Clock Frequency

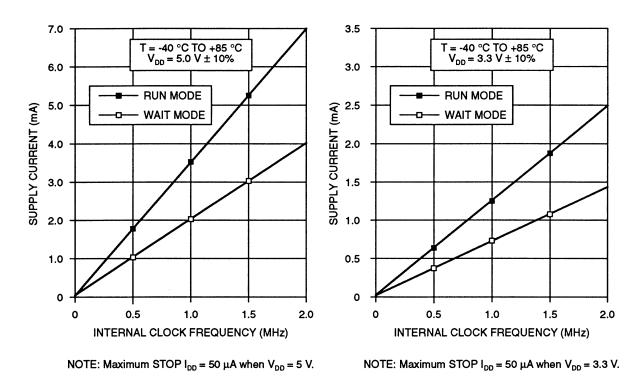


Figure 9-5. Maximum Supply Current vs Internal Clock Frequency

### APPENDIX A MC68HCL05P4

This appendix introduces the MC68HCL05P4, a low-power version of the MC68HC05P4. All of the information in *MC68HC05P4 Technical Data* applies to the MC68HCL05P4 with the exceptions given in this appendix.

#### A.1 DC ELECTRICAL CHARACTERISTICS

The data given in Table 9-3 and Table 9-4 of MC68HC05P4 Technical Data applies to the MC68HCL05P4 with the exceptions given in Table A-1, Table A-2, and Table A-3.

Table A-1. Low-Power Output Voltage (V<sub>DD</sub> = 1.8–2.4 Vdc)

Characteristic	Symbol	Min	Тур	Max	Unit
Output High Voltage (I <sub>LOAD</sub> = -0.1 mA) PA7-PA0, PB7-PB5, PC7-PC0, PD5, TCMP	V <sub>OH</sub>	V <sub>DD</sub> - 0.3	_	_	٧
Output Low Voltage (I <sub>LOAD</sub> = 0.2 mA) PA7-PA0, PB7-PB5, PC7-PC0, PD5, TCMP	V <sub>OL</sub>	_		0.3	٧

Table A-2. Low-Power Output Voltage (V<sub>DD</sub> = 2.5–3.6 Vdc)

Characteristic	Symbol	Min	Тур	Max	Unit
Output High Voltage (I <sub>LOAD</sub> = -0.2 mA) PA7-PA0, PB7-PB5, PC5-PC0, PD5, TCMP	V <sub>OH</sub>	V <sub>DD</sub> - 0.3			٧
Output Low Voltage (I <sub>LOAD</sub> = 0.4 mA) PA7-PA0, PB7-PB5, PC5-PC0, PD5, TCMP	V <sub>OL</sub>		_	0.3	٧

**Table A-3. Low-Power Supply Current** 

Characteristic	Symbol	Min	Typ <sup>(1)</sup>	Max	Unit
Supply Current ( $V_{DD}$ = 4.5–5.5 Vdc, $f_{OP}$ = 2.1 MHz) Run <sup>(2)</sup> WAIT <sup>(3)</sup> STOP <sup>(4)</sup>	I <sub>DD</sub>	_	3.1 1.1	4.25 2.25	mA mA
25 °C 0 °C to 70 °C (Standard)			2.0 —	15 25	μA μA
Supply Current (V <sub>DD</sub> = 2.5–3.6 Vdc, f <sub>OP</sub> = 1.0 MHz) Run <sup>(2)</sup> WAIT <sup>(3)</sup> STOP <sup>(4)</sup> 25 °C 0 °C to 70 °C (Standard)	I <sub>DD</sub>	= = =	0.8 0.35 0.6	1.6 1.0 5.0 10.0	mA mA μA μA
Supply Current (V <sub>DD</sub> = 2.5–3.6 Vdc, f <sub>OP</sub> = 500 kHz) Run <sup>(2)</sup> WAIT <sup>(3)</sup> STOP <sup>(4)</sup> 25 °C 0 °C to 70 °C (Standard)	I <sub>DD</sub>	_ _ _	400 200 0.6 —	800 500 5.0 10.0	μΑ μΑ μΑ μΑ
Supply Current (V <sub>DD</sub> = 1.8–2.4 Vdc, f <sub>OP</sub> = 500 kHz) Run <sup>(2)</sup> WAIT <sup>(3)</sup> STOP <sup>(4)</sup> 25 °C 0 °C to 70 °C (Standard)	I <sub>DD</sub>		300 200 0.3	600 400 2.0 5.0	μΑ μΑ μΑ μΑ

<sup>1.</sup> Typical values reflect average measurements at midpoint of voltage range at 25 °C.

<sup>2.</sup> Run (operating)  $I_{DD}$  measured using external square wave clock source with all inputs 0.2 V from rail. No dc loads. Less than 50 pF on all outputs.  $C_L$  = 20 pF on OSC2.

<sup>3.</sup> WAIT  $I_{DD}$  measured using external square wave clock source with all inputs 0.2 V from rail. No dc loads. Less than 50 pF on all outputs.  $C_L = 20$  pF on OSC2. All ports configured as inputs.  $V_{IL} = 0.2$  V,  $V_{IH} = V_{DD}$  - 0.2 V. OSC2 capacitance linearly affects WAIT  $I_{DD}$ .

<sup>4.</sup> STOP  $I_{DD}$  measured with OSC1 =  $V_{DD}$ . All ports configured as inputs.  $V_{IL}$  = 0.2 V,  $V_{IH}$  =  $V_{DD}$  - 0.2 V.

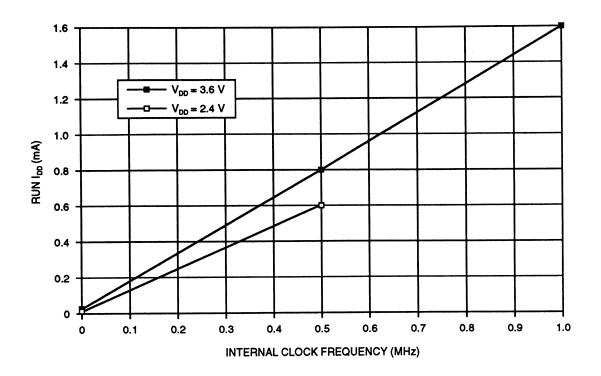


Figure A-1. Maximum Run Mode  $I_{\rm DD}$  vs Frequency

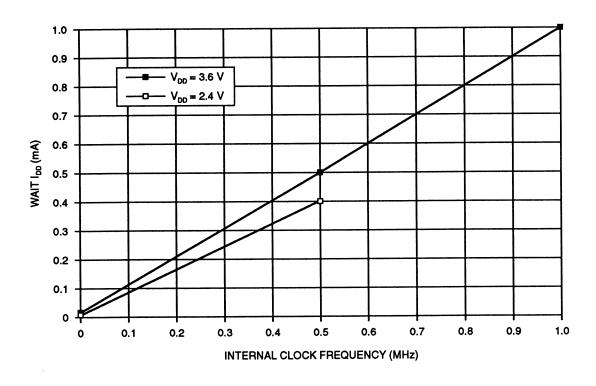


Figure A-2. Maximum WAIT Mode  $\mathbf{I}_{\mathrm{DD}}$  vs Frequency

#### A.2 MC Ordering Information

Table A-4 provides information for available package types.

**Table A-4. MC Order Numbers** 

Package Type	Temperature	MC Order Number
28-Pin Plastic Dual In-Line Package (DIP)	0° C to +70° C	MC68HCL05P4P
28-Pin Small Outline Integrated Circuit (SOIC)	0° C to +70° C	MC68HCL05P4DW

#### APPENDIX B MC68HSC05P4

This appendix introduces the MC68HSC05P4, a high-speed version of the MC68HC05P4. All of the information in MC68HC05P4 Technical Data applies to the MC68HSC05P4 with the exceptions given in this appendix.

#### **B.1 DC ELECTRICAL CHARACTERISTICS**

The data in Table 9-3 and Table 9-4 of MC68HC05P4 Technical Data applies to the MC68HSC05P4 with the exceptions given in Table B-1.

Table B-1. High-Speed Supply Current

Characteristic	Symbol	Min	Typ <sup>(1)</sup>	Max	Unit
Supply Current ( $V_{DD}$ = 4.5–5.5 Vdc, $f_{OP}$ = 4.0 MHz) Run <sup>(2)</sup> WAIT <sup>(3)</sup> STOP <sup>(4)</sup> 25 °C -40 to +85 °C	I <sub>DD</sub>	.	7.0 2.0 2.0	9.0 5.0 15 28	mA mA μA μA
Supply Current ( $V_{DD}$ = 3.0–3.6 Vdc, $f_{OP}$ = 2.1 MHz) Run <sup>(2)</sup> WAIT <sup>(3)</sup> STOP <sup>(4)</sup> 25 °C -40 to +85 °C	I <sub>DD</sub>	  -  -	1.8 0.8 0.6	5.0 2.5 5.0 12	mA mA μA μA

<sup>1.</sup> Typical values at midpoint of voltage range, 25 °C only.

<sup>2.</sup> Run (operating) I<sub>DD</sub> measured using external square wave clock source with all inputs 0.2 V from rail. No dc loads. Less than 50 pF on all outputs.  $C_L = 20$  pF on OSC2.

<sup>3.</sup> WAIT IDD measured using external square wave clock source with all inputs 0.2 V from rail. No dc loads. Less than 50 pF on all outputs.  $C_L = 20$  pF on OSC2. All ports configured as inputs;  $V_{IL} = 0.2$  V,  $V_{IH} = V_{DD}$  - 0.2 V. OSC2 capacitance linearly affects WAIT  $I_{DD}$ . 4. STOP  $I_{DD}$  measured with OSC1 =  $V_{DD}$ . All ports configured as inputs.  $V_{IL}$  = 0.2 V,  $V_{IH}$  =  $V_{DD}$  - 0.2 V.

#### **B.2 CONTROL TIMING**

The data given in Table 9-5 and Table 9-6 of MC68HC05P4 Technical Data applies to the MC68HSC05P4 with the exceptions given in Table B-2 and Table B-3.

Table B-2. High-Speed Control Timing ( $V_{DD}$  = 5.0 V  $\pm$  10%)

Characteristic	Symbol	Min	Max	Unit
Oscillator Frequency Crystal Oscillator External Clock	fosc	dc	8.0 8.0	MHz MHz
Internal Operating Frequency (f <sub>OSC</sub> + 2) Crystal Oscillator External Clock Option	f <sub>OP</sub>	dc	4.0 4.0	MHz MHz
Internal Clock Cycle Time	t <sub>cyc</sub>	250		ns
Capture/Compare Timer Input Capture Pulse Width	t <sub>TH</sub> , t <sub>TL</sub>	63	·	ns
Interrupt Pulse Width Low (Edge-Triggered)	t <sub>ILIL</sub>	63		ns
OSC1 Pulse Width	t <sub>OH</sub> , t <sub>OL</sub>	45		ns

Table B-3. High-Speed Control Timing ( $V_{DD}$  = 3.3 V  $\pm$  10%)

Characteristic	Symbol	Min	Max	Unit
Oscillator Frequency Crystal Oscillator External Clock	f <sub>osc</sub>	dc	4.2 4.2	MHz MHz
Internal Operating Frequency (f <sub>OSC</sub> + 2) Crystal Oscillator External Clock Option	f <sub>OP</sub>	dc	2.1 2.1	MHz MHz
Internal Clock Cycle Time	t <sub>cyc</sub>	480		ns
Capture/Compare Timer Input Capture Pulse Width	t <sub>TH</sub> , t <sub>TL</sub>	125		ns
Interrupt Pulse Width Low (Edge-Triggered)	t <sub>ILIL</sub>	125		ns
OSC1 Pulse Width	t <sub>OH</sub> , t <sub>OL</sub>	90		ns

#### **B.3 SIOP TIMING**

The data given in Table 9-7 and Table 9-8 of MC68HC05P4 Technical Data applies to the MC68HSC05P4 with the exceptions given in Table B-4 and Table B-5.

Table B-4. SIOP Timing (V<sub>DD</sub> = 5.0 V  $\pm$  10%)

Characteristic	Symbol	Min	Max	Unit
Clock (SCK) Low Time (f <sub>OP</sub> = 4.2 MHz)	t <sub>SCKL</sub>	466	_	ns
SDO Data Valid Time	t <sub>V</sub>		100	ns
SDO Hold Time	t <sub>HO</sub>	0	. —	ns
SDI Setup Time	t <sub>s</sub>	50	_	ns
SDI Hold Time	t <sub>H</sub>	50		ns

Table B-5. SIOP Timing ( $V_{DD}$  = 3.3 V  $\pm$  10%)

Characteristic	Symbol	Min	Max	Unit
Clock (SCK) Low Time (f <sub>OP</sub> = 2.1 MHz)	t <sub>sckl</sub>	990		ns
SDO Data Valid Time	t <sub>V</sub>	_	200	ns
SDO Hold Time	t <sub>HO</sub>	0	-	ns
SDI Setup Time	t <sub>s</sub>	100		ns
SDI Hold Time	t <sub>H</sub>	100		ns

#### **B.4 MC ORDERING INFORMATION**

Table B-6 provides information for available package types.

**Table B-6. MC Order Numbers** 

Package Type	Temperature	MC Order Number
28-Pin Plastic Dual In-Line Package (DIP)	0° C to +70° C -40° C to +85° C	MC68HSC05P4P MC68HSC05P4CP
28-Pin Small Outline Integrated Circuit (SOIC)	0° C to +70° C -40° C to +85° C	MC68HSC05P4DW MC68HSC05P4CDW

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